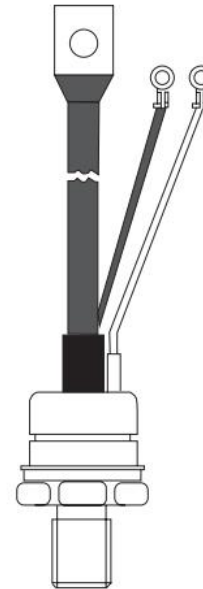


FEATURES

- Center amplifying gate
- Hermetic metal case with ceramic insulator
(Also available with glass-metal seal up to 1200 V)
- International standard case TO-209AB (TO-93)
- Compression Bonded Encapsulation for heavy duty operations such as severe thermal cycling
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers



ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	ST230S					UNIT
		04	08	12	14	16	
V_{RRM}	Repetitive Peak Reverse Voltage	400	800	1200	1400	1600	V
V_{RSM}	Non-Repetitive Peak Reverse Voltage	500	900	1300	1500	1700	V

SYMBOL	PARAMETER	CONDITIONS		VALUE	UNIT
$I_{T(AV)}$	Average Forward Current	$T_c=85^\circ\text{C}$, 180° conduction, half sine wave		230	A
$I_{T(RMS)}$	Maximum RMS on-state current	DC at 76°C case temperature		360	A
I_{TSM}	Max. peak, one-cycle forward, non-repetitive surge current	t = 10ms	No voltage reappplied	5700	A
		t = 8.3ms		5970	
		t = 10ms	100% VRRM reappplied	4800	
		t = 8.3ms		5000	
T_J	Junction Temperature			-40~125	°C
T_{stg}	Storage Temperature Range			-40~150	°C

THERMAL CHARACTERISTICS

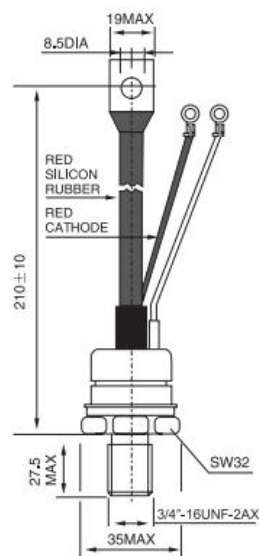
SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.105	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	TYPE	MAX	UNIT
V_{TM}	Forward Voltage Drop	$I_{pk} = 720\text{ A}$, $T_J = 125\text{ }^{\circ}C$, $t_p = 10\text{ ms}$ sine pulse		1.55	V
I_{DRM} I_{RRM}	Max. peak reverse and off-state leakage current	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied		30	mA
I_{GT}	DC gate current required to trigger	$T_J = -40\text{ }^{\circ}C$	180	150	mA
		$T_J = 25\text{ }^{\circ}C$	90		
		$T_J = 125\text{ }^{\circ}C$	40		
V_{GT}	DC gate voltage required to trigger	$T_J = -40\text{ }^{\circ}C$	2.9	3	V
		$T_J = 25\text{ }^{\circ}C$	1.8		
		$T_J = 125\text{ }^{\circ}C$	1.2		
t_q	Typical turn-off time	$I_{TM} = 300\text{ A}$, $T_J = T_J$ max, $di/dt = 20\text{ A}/\mu\text{s}$, $V_R = 50\text{ V}$, $dv/dt = 20\text{ V}/\mu\text{s}$, Gate 0V 100 Ω , $t_p = 500\text{ }\mu\text{s}$		100	μs

PACKAGE OUTLINE

Dimensions in mm (1mm = 0.0394")



*FOR METRIC DEVICES:
M20 × 1.5/M16 × 1.5-LENGTH21 MAX

Case Style TO-93

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